



Power-limits estimation example

- In this lesson, we look at Octave code to compute HPPC limits
- Code starts by loading data, configuring parameters

```
% Parameters
load('CellModel.mat');           % ESC cell model
load('CellData.mat');           % time/current/voltage/soc/spkfSOC/bounds

% Cell Configuration
T      = 25;                     % [degC] ambient temperature
Thorz  = 10;                    % [s] horizon time
z      = 0.5;                   % [] initial cell SOC
Ns     = 1;                     % [] number of series cells
Np     = 1;                     % [] number of parallel cells

% Operational Limits
zmin = 0.1;    zmax = 0.9;      % [] soc limits
vmin = 2.8;    vmax = 4.3;      % [V] voltage limits
imin = -200;   imax = 350;      % [A] current limits
pmin = -inf;   pmax = inf;      % [W] power limits
```



Find ΔT resistances

- Next, find effective dis/charge resistances over horizon ΔT
- Use 10C pulses to do so

```
% Effective Resistances
Q      = getParamESC('QParam',T,model);
iChg   = 10*Q*[zeros(5,1); -ones(Thorz,1); zeros(5,1)]; % [A] charge pulse
iDis   = 10*Q*[zeros(5,1); ones(Thorz,1); zeros(5,1)]; % [A] discharge pulse
[vk,~,~,~,~] = simCell(iChg,T,model,1,z,0,0); % 1 = sample period
dvChg   = max(vk)-vk(1);
iChg     = min(iChg);
RChg     = abs(dvChg/iChg);
fprintf('Rchg = %2.4f (mOhm)\n',1000*RChg);

[vk,~,~,~,~] = simCell(iDis,T,model,1,z,0,0); % 1 = sample period
dvDis   = min(vk)-vk(1);
iDis     = max(iDis);
RDis     = abs(dvDis/iDis);
fprintf('Rdis = %2.4f (mOhm)\n',1000*RDis);
```



HPPC truth power limits

- We now compute “truth” power limits using exact SOC from carefully calibrated lab tests

```
% HPPC Power Estimation: Truth
OCV     = OCVfromSOCtemp(soc,T,model);
iDisMaxV = (OCV-vmin)/RDis;
iDisMaxZ = (soc - zmin)*3600*Q/Thorz;
iDisMax  = max(0,min([iDisMaxV;iDisMaxZ;imax*ones(size(soc))]));
pDisMax  = min(vmin*iDisMax,pmax*ones(size(soc)));
iChgMinV = (OCV-vmax)/RChg;
iChgMinZ = (soc - zmax)*3600*Q/Thorz;
iChgMin  = max([iChgMinV;iChgMinZ;imin*ones(size(soc))]);
pChgMin  = min(0,max(vmax*iChgMin,pmin*ones(size(soc))));
HPPC.pDisMax = pDisMax;
HPPC.pChgMin = pChgMin;
```



HPPC SPKF power limits

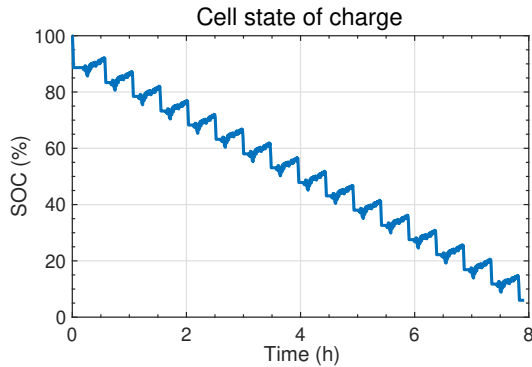
- We now compute more realistic power limits using SOC estimate and bounds produced by SPKF

```
% HPPC Power Estimation: SPKF
OCVDis = OCVfromSOCtemp(spKF SOC-bounds,T,model);
OCVChg = OCVfromSOCtemp(spKF SOC+bounds,T,model);
iDisMaxV = (OCVDis-vmin)/RDis;
iDisMaxZ = (spKF SOC-bounds - zmin)*3600*Q/Thorz;
iDisMax = max(0,min([iDisMaxV;iDisMaxZ;imax*ones(size(soc))]));
pDisMax = min(vmin*iDisMax,pmax*ones(size(soc)));
iChgMinV = (OCVChg-vmax)/RChg;
iChgMinZ = (spKF SOC+bounds - zmax)*3600*Q/Thorz;
iChgMin = max([iChgMinV;iChgMinZ;imin*ones(size(soc))]);
pChgMin = min(0,max(vmax*iChgMin,pmin*ones(size(soc))));
spKFHPPC.pDisMax = pDisMax;
spKFHPPC.pChgMin = pChgMin;
```



Example experiment

- We execute the code to view representative results
- A cell is subjected to a sequence of sixteen UDDS cycles, separated by discharge pulses and five-minute rests
- SOC increases by about 5 % during each UDDS cycle, but is brought down about 10 % during each discharge between cycles
- The entire normal operating range for this cell (10 % to 90 % SOC) is excited during the cell test



Parameters for test

- Experiment computes power for single cell, $N_s = 1$ and $N_p = 1$
- Cell has nominal capacity of 7.5 Ah, and $\Delta T = 10$ s for both charge and discharge
- Operational limits for the power calculations are listed
- Pulse resistances are found to be

$$R_{\text{dis},\Delta T} = 3.539 \text{ m}\Omega$$

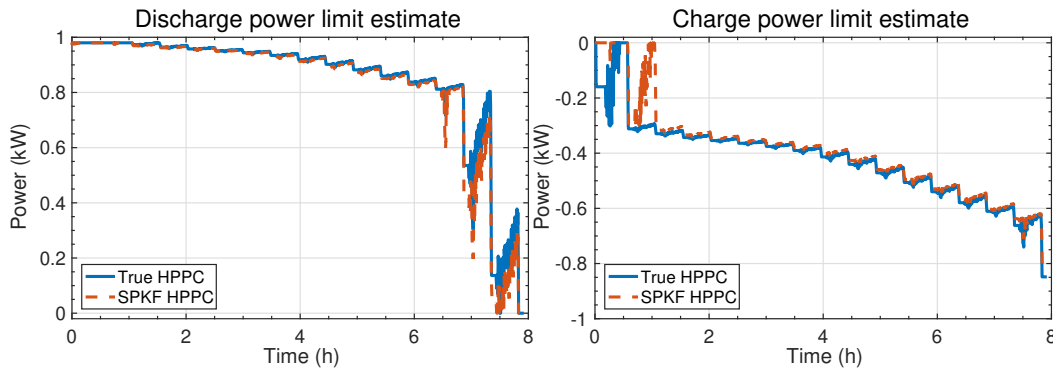
$$R_{\text{chg},\Delta T} = 3.517 \text{ m}\Omega$$

Parameter	Minimum	Maximum
$v_n(t)$	2.8 V	4.3 V
$i_n(t)$	-200 A	350 A
$z_n(t)$	0.1	0.9
$p_n(t)$	$-\infty$	∞



Results from running code

- Dis/charge power limits are plotted below
- SPKF method more conservative because uses bounds



Summary

- You have now learned how to write Octave code to compute HPPC power limits
- Code includes limits on future voltage, future SOC, current magnitude and power magnitude
- Example showed that limits are enforced on current, future SOC, and future voltage for a representative case
- SOC estimate plus bound produced by SPKF agree well with truth calculations, and produce slightly conservative estimates (good!)